NSN 5962-01-382-6954

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-382-6954

^	perating	Tomn	uratura	Pango:
J	perating	remp	urature	Kange:

-55.0/+125.0 degrees celsius

Inclosure Configuration:

Dual-in-line

Voltage Rating And Type Per Characteristic:

-0.5 volts applied and 8.0 volts applied

Special Features:

Memory cell

Terminal Type And Quantity:

14 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0